

	<b>DBs</b>
<b>1</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>2</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>3</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>4</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>5</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>6</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>7</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>8</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>9</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>10</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>11</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>12</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>13</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>14</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>15</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>16</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>

	<b>Ref #</b>	<b>Search Text</b>
<b>17</b>	<b>S17</b>	<b>S5 same S6</b>
<b>18</b>	<b>S18</b>	<b>S8 and S16 and S17</b>
<b>19</b>	<b>S19</b>	<b>("4742385"   "4827082"   "5027191"   "5311402").PN.</b>
<b>20</b>	<b>S20</b>	<b>("2005/0189632").URPN.</b>
<b>21</b>	<b>S21</b>	<b>("4603345"   "5032894"   "5281852"   "5324687"   "5401688"   "5410451"   "5448511"   "5459641"   "5552963").PN.</b>
<b>22</b>	<b>S22</b>	<b>("5776797").URPN.</b>
<b>23</b>	<b>S23</b>	<b>("5133495"   "5229916"   "5281852"   "5394303"   "5397916"   "5582326"   "5679977"   "5682061"   "5714405"   "5776797"   "5801446"   "5885549"   "5895970").PN.</b>
<b>24</b>	<b>S24</b>	<b>(bond\$3 seal\$3) near6 (die substrate S3)</b>
<b>25</b>	<b>S25</b>	<b>S5 with S24</b>
<b>26</b>	<b>S26</b>	<b>S7 same S25</b>
<b>27</b>	<b>S27</b>	<b>S2 same S25</b>
<b>28</b>	<b>S28</b>	<b>S25 with (via cavity opening)</b>
<b>29</b>	<b>S29</b>	<b>S2 same S28</b>
<b>30</b>	<b>S30</b>	<b>encapsulant near4 filler</b>
<b>31</b>	<b>S31</b>	<b>(silicone or polymer) with S30</b>
<b>32</b>	<b>S32</b>	<b>S31 and (@ad&lt;"20040301" @rlad&lt;"20040301")</b>
<b>33</b>	<b>S33</b>	<b>S31 same glob</b>

	<b>DBs</b>
<b>17</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>18</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>19</b>	<b>US-PGPUB; USPAT; USOCR</b>
<b>20</b>	<b>USPAT</b>
<b>21</b>	<b>US-PGPUB; USPAT; USOCR</b>
<b>22</b>	<b>USPAT</b>
<b>23</b>	<b>US-PGPUB; USPAT; USOCR</b>
<b>24</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>25</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>26</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>27</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>28</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>29</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>30</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>31</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>32</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>
<b>33</b>	<b>US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB</b>

	<b>Ref #</b>	<b>Search Text</b>
<b>1</b>	<b>S1</b>	<b>("seal\$3encapsulat\$3").PN.</b>
<b>2</b>	<b>S2</b>	<b>seal\$3 encapsulat\$3</b>
<b>3</b>	<b>S3</b>	<b>((S1 adj2 "D") or (three near3 dimension\$3)) near6 ((metal near3 bond\$3 near4 ("ic" or (integrated near3 circuit))) or (bond\$3 near4 ("ic" or (integrated near3 circuit))) or ("ic" or (integrated near3 circuit))))</b>
<b>4</b>	<b>S4</b>	<b>connector (control\$3 near3 collaps\$4 near3 chip) "C4" (solder near3 (ball bump))</b>
<b>5</b>	<b>S5</b>	<b>(contact near3 pad) (copper near3 (contact or pad))</b>
<b>6</b>	<b>S6</b>	<b>(bond\$3 seal\$3) near6 (die substrate)</b>
<b>7</b>	<b>S7</b>	<b>S5 with S6</b>
<b>8</b>	<b>S8</b>	<b>S2 same S3</b>
<b>9</b>	<b>S9</b>	<b>S2 with S3</b>
<b>10</b>	<b>S10</b>	<b>die substrate</b>
<b>11</b>	<b>S11</b>	<b>die substrate wafer</b>
<b>12</b>	<b>S12</b>	<b>S4 with S10</b>
<b>13</b>	<b>S13</b>	<b>S4 with S11</b>
<b>14</b>	<b>S14</b>	<b>S13 and S9 and S7</b>
<b>15</b>	<b>S15</b>	<b>S13 and S9</b>
<b>16</b>	<b>S16</b>	<b>S4 same S11</b>